L Number	Hits	Search Text	DB	Time stamp
1	2835863	memory or storage	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 15:01
2	140401	(memory or storage) and (nonvolatile or non-volatile or floating adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 15:03
3	2068	((memory or storage) and (nonvolatile or non-volatile or floating adj gate)) and capacitor and flip-flop	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 15:03
4	2	(((memory or storage) and (nonvolatile or non-volatile or floating adj gate)) and capacitor and flip-flop) and transistor with charge with capacitor with gate with boost$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 15:05
5	4	(((memory or storage) and (nonvolatile or non-volatile or floating adj gate)) and capacitor and flip-flop) and charge with capacitor with gate with boost$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/24 15:05